NSN 5961-00-826-0799

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-826-0799 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current and 10.00 milliamperes source cutoff current blank **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release2918 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No